C om parative Study of the Insulator-H all Liquid-Insulator Transitions: C om posite B oson P icture vs C om posite Ferm ion P icture

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Based on a new ly advanced phenom enological understanding of the high-eld insulator-Hall liquid transition in a composite ferm ion picture, we extend its composite boson counterpart to the analysis of the low-eld insulator-Hall liquid transition. We thus achieve a comparative study of these two transitions. In this way, the sim ilar rejection symmetries in

lling factors in both transitions are understood consistently as due to the sym m etry of the gapful excitations which dom – inate $_{xx}$ across the transitions, and the abrupt change in $_{xy}$ at the transitions. The substantially di erent characteristic energy scales involved in these two transitions can be attributed to the di erences in critical lling factors $_{c}$ and the e ective m asses. The opposite tem perature-dependences of the critical longitudinal resistivities are also well-understood, which can be traced to the opposite statistical natures of the com posite ferm ion and the com posite boson. W e also give a tentative discussion of the zero-tem perature dissipative conductivity. The above results are supported by a recent experim ent (cond-m at/9708239).

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The study of the magnetic eld induced insulator Hall liquid transitions has evoked considerable interests in the past decade. In the theoretical aspect, K ivelson, Lee and Zhang (KLZ) [1] started from the bosonic Chem-Sim ons eld theory [2] and gave an elegant derivation which lead to the overall phase diagram of the general quantum Hall system with respect to disorder and magnetic eld. A qualitatively identical phase diagram was obtained by Halperin, Lee and Read $[\beta]$, from the celebrated composite ferm ion (CF) theory [4]. The well-known correspondence rule advanced by KLZ established a series of connections between the plateau-plateau transitions and the insulator-Hall liquid transitions, which suggests the possibility of super-universality [5] in the diverse quantum phase transitions observed in the quantum Hall system [6] [7]. M any experiments have been conducted to check these ideas [8].

In a recent experiment [9], Hilke et al. examined the magnetic eld driven insulator-quantum Hall liquidinsulator transitions of the two dimensional hole system (2DHS) in a Ge/SiGe quantum well. With the increase of magnetic eld, they found interesting similarities between the low - eld (LF) insulator-Hall liquid transition and the high-eld (HF) Hall liquid-insulator transition, with respect to the transport properties. First, the critical longitudinal resistivity at the LF transition $\frac{L}{c}$ and the one at the HF transition $\frac{L}{c}$ are approximately equal(Fig.1),

 ${}^{\rm L}_{\rm C} = {}^{\rm H}_{\rm C} 3\%$:

Secondly, there is a rejection symmetry in $_{xx}$ at the LF transition similar to the one at the HF transition previously reported by Shahar et al. [10]. These relations can be tted by the following equations (Fig.2):

$$L_{xx}(;T) = L_{c} \exp\left[-\frac{L}{0}(T)\right]; \qquad (1)$$

where = ${}_{c}^{L}$, ${}_{0}^{L}$ (T) = ${}^{L}T$ + L , and L , L are sam ple-dependent param eters;

$$_{xx}^{H}(;T) = {}_{c}^{H} \exp\left[\frac{1}{0}(T)\right]; \qquad (2)$$

where = ${}^{H}_{c}$, ${}^{H}_{0}$ (T) = H T + H and H , H are sample-dependent parameters;

In spite of the above similarities which suggest similarm echanisms for the two transitions, Hilke et al. also pointed out several di erences between the HF transition and the LF transition: First, there are quite different characteristic energy scales involved in these two transitions, i.e.

$$^{L} = ^{H}$$
 0:19=0:03 6;

as the m easurement in ref [9] showed (see FIG 2). Secondly, the temperature-dependences of $_{c}^{L}$ and $_{c}^{H}$ are opposite, with the form er decreasing with higher T while the later increasing with higher T. B oth behaviors show up when T is larger than certain threshold values (FIG 1).

The similar properties of the LF transition and the HF transition seem to favor the oating up recipe [11], where both transitions are attributed to the crossing of the Ferm i level with the lowest extended level. However, the substantially di erent energy scales and the qualitatively opposite T -dependences in the critical resistivities are beyond its predictions. It will be the aim of this paper to present a consistent phenom enological picture accounting for the above similarities and di erences.

In a recent paper [12], we present a phenom enological picture based on the composite ferm ion theory, in order to understand the rejection symmetry near the transition from a = 1 quantum H all liquid to a H all insulator (the above-mentioned HF transition). In that picture, the seem ingly unexpected rejection symmetry in the longitudinal resistivity xx can be understood clearly as due

to the symmetry of the gapful excitations which dominate $_{xx}$ across the transition, and the abrupt change in $_{xy}$ at the transition. The parameter in the linear t of $_0$ (T) in ref [10] is also given a simple physical meaning. Based on that theory the elective mass can be calculated from , which gives a reasonable value of several electron band mass. When taking into account the previous network model calculations, the nearly invariant H all resistivity $_{xy}$ across the transition is also well-understood.

O ne can see that the above picture does not directly depend on the statistical nature of the CFs. That is to say, the CB counterpart of it will produce the same re ection symmetry in $_{xx}$. Based on this consideration, we attempt to use this CB picture to describe the LF transition, and then give an explanation of the properties that are di erent from the HF transition.

Noticing that the critical magnetic eld at the HF transition $B_{c}^{H} = 4.04T$ is alm ost twice the value at the LF transition $B_c^L = 1.975T$, we argue that the one-uxquanta bound com posite boson w illalso be a kind ofgood quasiparticle near the LF transition, under the condition that the two-ux-quanta bound com posite ferm ion is useful in accounting for the transport properties near the HF transition. Because the landau level (LL) m ixing is more severe near the LF transition with relatively larger disorder and sm aller LL spacing, the measured critical lling factor $\frac{L}{c} = 1:77$ deviates much from the ideal low est LL constrained factor 1. We ignore here the possible contribution of the particles from the second LL. Therefore, we can suppose that at the LF transition, there are wellde ned CBs in a zero e ective magnetic eld, while the CBswill feel the energy gap induced by the e ective magnetic eld B when deviates from $^{L}_{C}$ a little. So we have

$$_{xx}(;T) / _{xx}^{CB}(;T) / \exp(!_{c}=k_{B}T);$$
 (3)

where $!_{c} = \frac{heB}{m_{CB}} / j$ $^{L}_{c} jh$ is set to unit, and the rst relation is derived from the transform ation between electrons and CBs given by ref [1].

In spite of the above continuity and symmetry around $_{c}^{L}$, there should be however a sharp change in the Hall conductivity $_{xy}$ across the LF transition point. For $< _{c}^{L}$ or the quantum Hall liquid phase, we have $_{xy} = e^2 = h$ (T ! 0); while for $> _{c}^{L}$ or the insulator phase, we get $_{xy}$! 0 (T ! 0). This is also consistent with the well-known " oating up" recipe [11], where the QHL-Insulator transition occurs at the crossing of the Ferm i level with the lowest extended states and $_{xy}$ is determined by the number of extended states below the Ferm i level.

W ith the above results of conductivity, W e can obtain the resistivity tensor by conducting an inversion of the conductivity tensor, that is

$$_{XX} = \frac{_{XX}}{_{XX}^2 + _{XY}^2}$$
: (4)

When < 0,

$$xx = \frac{xx}{2}$$

$$xy = \frac{x}{2}$$

$$xy = \frac{1}{2}$$

$$xx = \frac{1}{2}$$

$$xy = \frac{1}{2$$

When > 0,

$$xx \quad xx \quad xx \quad (6)$$

$$/ \exp(!_{c} = k_{B} T):$$

C om bining the above results and the relation $!_{c} / j j$ we can easily identify the relation symmetry,

$$_{\text{xx}}^{\text{L}}$$
 (;T) = $_{\text{c}}^{\text{L}} \exp\left[-\frac{1}{T}\right]$;

where

$${}^{\rm L} = \frac{2 \, k_{\rm B} \, m_{\,\rm C \, B} \, {}^{\rm L \, 2}_{\rm C}}{h^2 n}; \qquad (7)$$

n is the density of the 2D HS.A fler taking into account the corresponding result for the HF transition (the case of CFs), we have

$$\frac{L}{H} = \frac{\frac{L^2}{c}}{\frac{H^2}{c}} \frac{m_{CB}}{m_{CF}};$$

Since ${}_{c}^{L}$ 2 ${}_{c}^{H}$ contributes a factor 4 in the ratio ${}^{L}={}^{H}$ 6, we can attribute the substantially di erent energy scales between the LF transition and the HF transition as mainly due to the variant ${}_{c}$. Besides, we also expect $\frac{m}{m}_{cF}$ to be larger than 1, because of the different extents of disorder for CFs and CBs(see below). In this respect the above theory is consistent with the experimental result of the ratio ${}^{L}={}^{H}$ 6:

In another way, one can use the data from ref [9] to estimate the e ective masses m_{CB} and m_{CF}. Substitute $n = 0.87 \quad 10^{11}$ cm², ^H = 0.03K¹ and ^L = 0.19K¹ into eq (7) and its counterpart for CFs in the HF transition, one can get,

$$m_{CB}$$
 $9m_{b}$; m_{CF} $6m_{b}$;

which give reasonable values of several band m ass for $m_b = 0:1m_e$. This fact gives support to our usage of the CB (CF) picture in the LF (HF) transition.

Then let us turn to the discussion of the critical longitudinal resistivity $_{c}^{H}$ and $_{c}^{L}$. At the critical point of the HF (LF) transition, the elective magnetic eld B is averaged to zero. To get started, we adopt the sim plest picture of free CFs (CBs) moving in a random potential. This picture is not as easy as it seems to be, because the disorder is relatively strong. (From the measurement, $_{\rm C}$ 22h=e², so k_F l is of the order of l or less, which has reached the IR lim ±). Therefore, for the case of CFs, we can expect the D rude form ula to hold at most m arginally, which gives:

$$C_{c}^{CF} = ev_{F} \frac{dn}{dE} (el_{CF})$$

$$= ev_{F} \frac{n}{E_{F}} (el_{CF})$$

$$= ev_{F} \frac{k_{F}^{2}}{4 E_{F}} (el_{CF})$$

$$/ \frac{e^{2}}{h} (k_{F} l_{CF}):$$
(8)

One can see that $^{\rm H}_{\rm c}$, or its inversion $^{\rm C\,F}_{\rm c}$ is uniquely determ ined by a single dimension-less parameter $k_F \mathrel{l_{c}}_F$, which m easures the extent of disorder. W e then m ake a reasonable extension of the above conclusion to the case of CBs, with k_F substituted by the typical wave vector $k_{C\,B}\,$ speci c to the CBs and $l_{C\,F}\,$ substituted by its CB counterpart $l_{\!C\,B}$, W e note that $k_{\!C\,B}\,$ is much sm aller than $k_{\rm F}$ at a tem perature T << E $_{\rm F}$ (we avoid applying the D rude form ula directly to the CBs, because its wavelength is much larger than $k_{\rm B}$, and the classical picture is no longer valid). If we suppose that the mean free path is alm ost the same for CFs and CBs, then this dimensionless parameter for CBs will be much smaller than that for CFs. Therefore the localization e ect of disorder is more severe on CBs than on CFs. So we can expect the disorder potential induced e ective mass for CBs to be larger than its counterpart for CFs. This is consistent with above calculation of $m_{CB} = m_{CF}$ 1:5.

The above "single param eter" argum ent can also be applied to the qualitative analysis of the tem peraturedependences of the critical resistivities $\frac{H}{C}$ and $\frac{L}{C}$. Let us rst suppose a sim ilar T-dependence in the m ean free paths for CFs and CBs (that is, they decrease as T increases). Then for the CF case, only CFs near the Ferm i surface have contributions to the transport properties, with momentum k_F almost independent of T. So the param eter $k_F \downarrow_{CF} w$ ill decrease as T increases, which in plies that $\frac{H}{c}$ will increase as T goes up. In contrast, for the case of CBs, an increase in T will excite the CBs from low momentum states to higher momentum ones, which results in a considerable increase in k_{CB} that can counteract the decrease in l_{CB} [13], so the overall tendency for the parameter $k_{C B} \downarrow_{C B}$ will be an increment. Therefore $_{
m c}^{
m L}$ will increase as T goes up. In this way, one can see that the opposite T -dependences in $^{\rm H}_{\rm c}$ and $^{\rm L}_{\rm c}$ com e from the presence of a Ferm i surface in the CFs and the absence of one in the CBs, which has its origin from the opposite statistical natures of ferm ions and bosons. Based on this speculation, we suggest doing the sam e m easurement on a sample with its density 10 times smaller and in the same range of tem perature (OK to 10K). In this

case, E $_{\rm F}\,$ will be of the same order of T , and the Ferm i surface e ect will be weakened considerably. Therefore the di erent T -dependences between ${}^{\rm H}_{\rm c}$ and ${}^{\rm L}_{\rm c}$ should disappear.

Then we comment brie y on the relation between $\stackrel{H}{\underset{c}{}^{c}}$ and $\stackrel{L}{\underset{c}{}^{c}}$ at T = 0. The possible universal relation $\stackrel{H}{\underset{c}{}^{c}}$ (T = 0) = $\stackrel{L}{\underset{c}{}^{c}}$ (T = 0), as suggested by Hilke at el. can not be understood easily in the present picture, because it is di cult to give a reliable analytical equation for a strongly disordered, non-interacting bosonic system. Num ericalm ethods form odel calculations are suitable in this respect, which will be the focus of our future work.

We then turn to a tentative discussion of the origin of the zero-tem perature dissipative conductivity re ected from the non-zero $^{\rm H}$ and $^{\rm L}$. A coording to our phenom enological picture, near the HF (LF) transition, CFs (CBs) move under an elective magnetic eld B . In the single particle approximation, the CFs or CBs reside on the nearly localized quantum Hall states whose spatial distributions are proportional to exp($(x \ X)^2=21_{\rm B}^2$) with the center X distributes almost uniform ly across the plane, where $l_{\rm B}$ is the magnetic length corresponding to B . At the zero temperature limit, we expect quantum tunnelings between the quantum H all states to dom inate the transport properties. Therefore we suggest that the average tunneling probability p(T = 0) which is proportional to $_{\rm xx}$ (T = 0), is determined by

$$p(T = 0) / exp(d^2 = 2l_B^2)$$

where d is the average distance between adjacent particles, or d 1 = n. Then by using the following relations:

$$l_{B} = \frac{r}{\frac{h}{eB}}; = nh=eB; = \frac{c}{jj}$$

we can easily arrive at

$$_{xx}$$
 (T = 0) / exp($\frac{j}{c}$)

Therefore we can estimate

2 c

O ne can compare the above result with the experimentally determined $^{\rm H}$ and $^{\rm L}$ by substituting $_{\rm c}$ = 1=2 and 1 for the HF and LF transitions respectively. The theoretical values are

^H 0:08; ^L 0:3;

which give a suprisingly good twith the experimental data (see Fig.2). We comment that in Fig.2b the residue value of $_0$ should be much closer to 0.3 considering the attening tendency of the dots when approaching T = 0. As we believe, the above consistency should be a very

strong support to our seem ingly naive understandings based on CF and CB respectively.

Before closing, let us give the follow ing com m ents in order. First, let us comment on the metallic T-dependence for $\frac{H}{c}$, which is described here in the fram ework of free CFs in a random potential without a magnetic eld. A ccording to the conventional belief [14], a two dim ensional non-interacting system will be localized to an insulator upon the introduction of an in nitesim alextent of disorder, so the metallic phase is absent. However, the situation here is quite di erent. Because of the gauge uctuations in the CF system which break the tim e-reversal symmetry, the weak localization e ect [15] that leads to the localization is suppressed. Therefore it is still possible for the CF system to demonstrate metallic behaviors at the lim it $k_F \downarrow_{CF}$ 1. Then, let us discuss the role of the Coulomb interaction in the CF system. In a low-density disordered two dim ensional system, C oulom b gap has im portant consequences in transport properties (i.e. a hop- $\frac{T_0}{T}$)) [16]. But the e ect of ping conductivity exp (Coulom b interaction is di erent for CFs. Since the particles are con ned to the lowest LL, the CF e ective m ass has its source from interaction and disorder. In Read's recipe [17], the residue interactions between the CFs (the alm ost neutral ux-hole-electron triplet) are reduced considerably. So the e ect of C oulom b interaction is mainly absorbed into the e ective m ass of the CFs. To be com plete, we do not exclude the interaction induced ln (T) correction to the conductivity [18], which is supposed to be in portant at quite low tem perature and irrelevant to the experim ent here (the T-dependence of $^{\rm H}_{\rm c}$ m anifests for T larger than 3K). As for the CB system, we believe that the above comments are probably also applicable. Finally, we would like to suggest that both CFs and CBs are good quasiparticles in quantum Hall systems, and they are not simply equivalent to each other, nor do they exclude each other. They assume dom ination in di erent regim es of the phase diagram, with the excitation energy scales close to the minimum. Because of the opposite statistical natures of CFs and CBs, we can expect m any diverse properties to be observed, which will be the task of the future experim entalists.

In conclusion, we have extended a new ly advanced CF picture of the high-eld insulator-H all liquid transition to its CB counterpart, which is then applied to the analysis of the low - eld insulator-H all liquid transition. We thus present a comparative study of these two transitions. In this way, the sim ilar rejection symmetries in lling factors in both transitions are understood consistently as due to the symmetry of the gapful excitations which dom - inate $_{xx}$ across the transitions, and the abrupt change in $_{xy}$ at the transitions. The substantially di erent characteristic energy scales involved in these two transitions can be attributed to the di erences in critical lling factors $_{c}$ and the elective masses. The opposite temperature-

dependences of the critical longitudinal resistivities are also well-understood, which can be traced to the opposite statistical natures of the composite ferm ion and the composite boson. We also give a tentative discussion of the zero-tem perature dissipative conductivity, and arrive at a good t with the experiment.

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FIG.1. Tem perature dependence of the resistivities around the low and high eld transitions. In g.2 a) the magnetic elds corresponding to the central resistivity curves are 3.94, 4.04 and 4.14 T and in g.2 b) they are 2.05, 1.975 and 1.9 T (reprinted from ref[9]).

FIG.2. $_0$ (T) on a linear graph as a function of tem perature T for the high-eld transition. The inset shows the low-eld transition up to 1.7 K. The straight lines are linear ts to the data (reprinted from ref[9]).

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